Republic of Iraq

The Ministry of Higher Education

& Scientific Research



University: Diyala College: Engineering

Department: Computer and S/W

Stage: First

Lecturer name: Saad M. Saleh Academic Status: Lecturer

Qualification: PhD

Place of work: Computer Dept.

Flow up the implementation of course syllabus

Course Instructor	Saad Mohammed Saleh					
E_mail	saad_alazawi@yahoo.com					
Title	Electronic Engineering					
Course Coordinator						
Course Objective	To teach student the main information about: Semiconductors, PN-Junction, Diodes, Diode applications, BJT and FET.					
Course Description	It introduces the essential information about Electronic Engineering. This includes; Semiconductors, PN-Junction, Diode and its application, BJT and its biasing circuits and equivalent circuits and the FET.					
Textbook	Electronic Devices and Circuit Theory by Bolyested Other resources: Electrical Technology by Theraja Other lectures notes on the Internet Network					
Course Assessment	First Term	Mid-Year	Ynd Term	Project	Final Exam	
	١٠ %	۲۰%	١٠%		٦٠ %	
General Notes	Type here general notes regarding the course					

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Course Weekly Outline

week	Date	Topics Covered	Lab. Experiment Assignments	Notes			
١ ،	19/11/7.15	Introduction					
۲	Y 7/1 1/Y • 1 £	Insulator, Conductors, Semiconductors					
٣	. ٣/١ ٢/٢ . ١ ٤	P.N Junction					
£	1./17/7.15	Diode types					
٥	1 4/1 4/4 • 1 5	Half wave rectifier					
٦	7	Full wave rectifier					
٧	W1/17/Y . 1 £	Clipping circuits					
٨	. ٧/. ١/٢ . ١ ٥	Clamping circuits					
	Mid-Year Break						
٩	1	Bipolar Junction Transistors					
١.	۲٥/٠٢/٢٠١٥	Basic transistor operation					
11	. ٤/. ٣/٢ . ١٥	BJT configurations					
١٢	11/. 4/7.10	BJTS basing circuits					
١٣	1	BJTS basing circuits					
١٤	۲٥/٠٣/٢٠١٥	BJT transistor modeling					
10	.1/. £/٢.10	RE transistor model					
١٦	٠٨/٠٤/٢٠١٥	Hybrid Equivalent model					
١٧	10/. 2/7.10	FET Construction					
١٨	Y Y / · £ / Y · 1 0	FET Operation					
١٩	Y9/. £/Y. 10	FET Biasing					
۲.	.7/.0/7.10	FET Biasing					
۲۱	17/.0/7.10	FET Biasing					
77	7./.0/7.10	FET Small-Signal Analysis					

7 7	YV/.0/Y.10	FET Small-Signal Analysis	
۲ ٤	. 4/. 7/7.10	FET Small-Signal Analysis	

Instructor Signature:

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